NSN 5962-01-332-8593

Memory Microcircuit - Page 1 of 2



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Between 1.440 inches and 1.485 inches

Overall Height:

0.395 inches

Overall Width:

Between 0.620 inches and 0.700 inches

Body Length:

Between 1.440 inches and 1.485 inches

Body Width:

Between 0.515 inches and 0.605 inches

Body Height:

Between 0.140 inches and 0.195 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and programmed and ultraviolet erasable and low power and w/disable and w/enable and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Hi-performance mos

Input Circuit Pattern:

16 input

Current Rating Per Characteristic:

100.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.6 volts power source and 13.0 volts power source

Capitance Rating Per Characteristic:

6.00 input picofarads and 12.00 output picofarads

Time Rating Per Chacteristic:

250.00 nanoseconds af output megawatts

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

NSN 5962-01-332-8593

Memory Microcircuit - Page 2 of 2



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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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